

New Product

P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$r_{DS(on)}\left(\Omega\right)$	I _D (A)		
- 30	0.0085 at $V_{GS} = -10 \text{ V}$	– 18		
	0.013 at V _{GS} = - 4.5 V	- 14		

FEATURES

- TrenchFET[®] Power MOSFETS
- New Low Thermal Resistance PowerPAK® Package with Low 1.07-mm Profile



COMPLIANT

APPLICATIONS

- Battery and Load Switching
 - Notebook and Tablet Computers
 - Notebook and Tablet Battery Packs

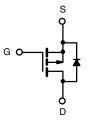
6.15 mm

PowerPAK SO-8

Bottom View

Ordering Information: Si7491DP-T1

Si7491DP-T1-E3 (Lead (Pb)-free)



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted					
Parameter		Symbol	10 secs	Steady State	Unit
Drain-Source Voltage		V_{DS}	- 30		V
Gate-Source Voltage		V_{GS}	± 20		
Continuous Drain Current (T 150 °C)8	T _A = 25 °C	- I _D	- 18	- 11	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 14	- 8	Α
Pulsed Drain Current		I _{DM}	- 50		1
Continuous Source Current (Diode Conduction) ^a		l _S	- 4.5	- 1.6	
Maximum Power Dissipation ^a	T _A = 25 °C	P _D	5	1.8	W
Maximum Power Dissipation	T _A = 70 °C		3.2	1.1	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C
Soldering Recommendations (Peak Temperature) ^{b,c}		-	2	60	C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Mariana languian ta Andrianda	t ≤ 10 sec	R _{thJA}	20	25	°C/W	
Maximum Junction-to-Ambient ^a	Steady State		54	68		
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	1.7	2.2		

a. Surface Mounted on 1" x 1" FR4 Board.
b. See Solder Profile (http://www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply.

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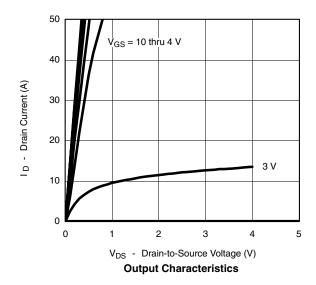


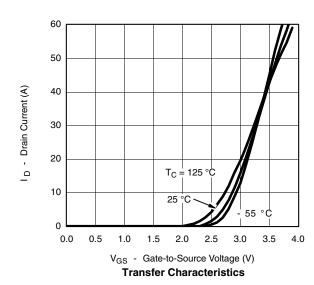
SPECIFICATIONS $T_J = 25$ °C, unless otherwise noted							
Parameter	Symbol	Test Condition	Min	Тур	Max	Unit	
Static							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250 \mu A$	- 1.0		- 3.0	V	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zava Cata Valtaga Drain Current	I _{DSS}	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$		- 1		4	
Zero Gate Voltage Drain Current		$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$			- 10	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	- 30			Α	
	r	$V_{GS} = -10 \text{ V}, I_D = -18 \text{ A}$		0.007	0.0085	0	
Drain-Source On-State Resistance ^a	r _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -14 \text{ A}$		0.0105	0.013	Ω	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = -15 \text{ V}, I_{D} = -18 \text{ A}$		46		S	
Diode Forward Voltage ^a	V_{SD}	$I_S = -4.5 \text{ A}, V_{GS} = 0 \text{ V}$		- 0.74	- 1.1	V	
Dynamic ^b				1			
Total Gate Charge	Q_g			56	85		
Gate-Source Charge	Q _{gs} Q _{gd}	$V_{DS} = -15 \text{ V}, V_{GS} = -5 \text{ V}, I_{D} = -18 \text{ A}$		12		nC	
Gate-Drain Charge				25			
Turn-On Delay Time	t _{d(on)}			150	225		
Rise Time	t _r	$V_{DD} = -15 \text{ V}, R_L = 15 \Omega$		190	290		
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ – 1 A, V_{GEN} = – 4.5 V, R_G = 6 Ω		120	180		
Fall Time	t _f			90	140	ns	
Gate Resistance	R_g			2.5			
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = -2.9 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$		50	80		

- Notes a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless noted

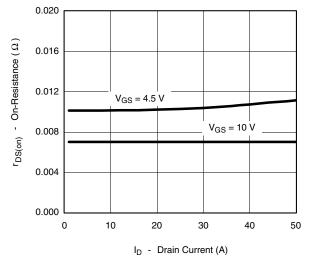




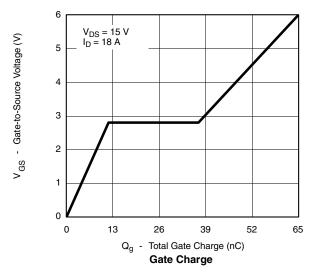
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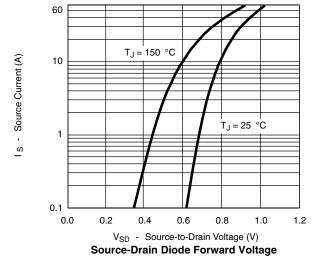
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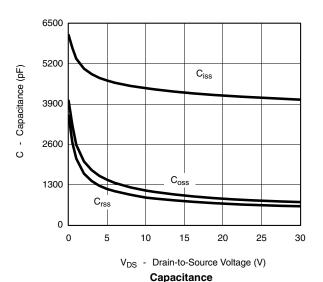
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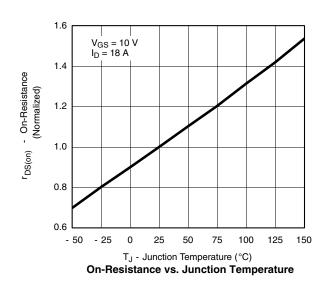


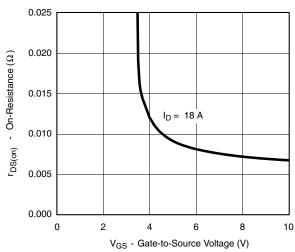
On-Resistance vs. Drain Current











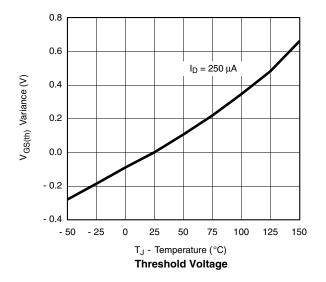
On-Resistance vs. Gate-to-Source Voltage

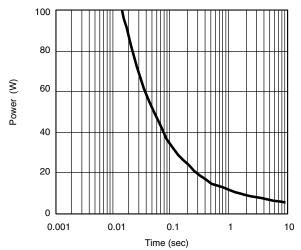
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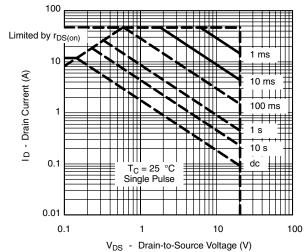


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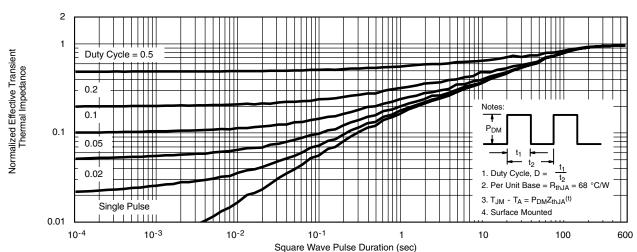




Single Pulse Power, Junction-to-Ambient



Safe Operating Area, Junction-to-Case

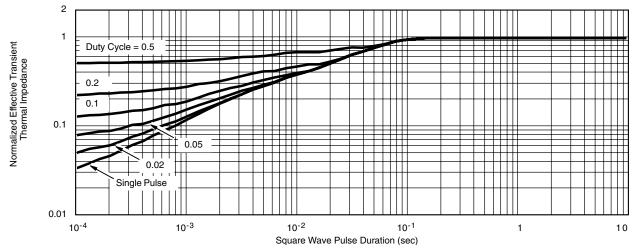


Normalized Thermal Transient Impedance, Junction-to-Ambient

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TYPICAL CHARACTERISTICS 25 °C, unless noted



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?72276.

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